

P-Channel Enhancement Mode MOSFET

Feature

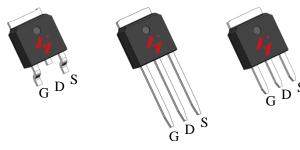
• -60V/-40A

 $R_{DS(ON)} = 19m\Omega(typ.) @V_{GS} = -10V$

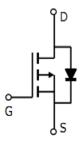
 $R_{DS(ON)} = 25m\Omega(typ.) @V_{GS} = -4.5V$

- 100% avalanche tested
- Reliable and Rugged
- Halogen Free and Green Devices Available (RoHS Compliant)

Pin Description



TO-252-2L TO-251-3L TO-251-3S

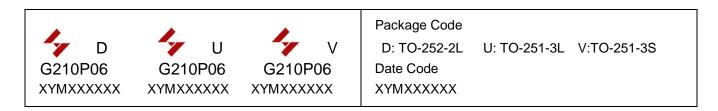


P-Channel MOSFET

Applications

- Power Management in DC/DC
- Load switching.
- Motor control.

Ordering and Marking Information



Note: HUAYI lead-free products contain molding compounds/die attach materials and 100% matte tin plate Termination finish; which are fully compliant with RoHS. HUAYI lead-free products meet or exceed the lead-Free requirements of IPC/JEDEC J-STD-020 for MSL classification at lead-free peak reflow temperature. HUAYI defines "Green" to mean lead-free (RoHS compliant) and halogen free (Br or Cl does not exceed 900ppm by weight in homogeneous material and total of Br and Cl does not exceed 1500ppm by weight).

HUAYI reserves the right to make changes to improve reliability or manufacturability without notice, and Advise customers to obtain the latest version of relevant information to verify before placing orders.



Absolute Maximum Ratings

Symbol	Parameter	Rating	Unit	
Common Ra	tings (Tc=25°C Unless Otherwise Noted)		•	1
VDSS	Drain-Source Voltage		-60	V
Vgss	Gate-Source Voltage		±20	V
TJ	Junction Temperature Range		-55 to 175	°C
Тѕтс	Storage Temperature Range		-55 to 175	°C
ls	Drain Current-Continuous	Tc=25°C	-40	А
Mounted on	Large Heat Sink	-		•
Ірм	Pulsed Drain Current *	Tc=25°C	-140	А
ID	Continuous Dunin Comment	Tc=25°C	-40	А
ID	Continuous Drain Current	Tc=100°C	-28	А
_	Maximum Davida Discination	Tc=25°C	60	W
Po	Maximum Power Dissipation Tc=100°C		30	W
R _{uc}	Thermal Resistance, Junction-to-Case		2.5	°C/W
$R_{ heta A}$	Thermal Resistance, Junction-to-Ambient **		110	°C/W
Eas	SinglePulsed-Avalanche Energy ***	L=0.3mH	289***	mJ

Note: *

- * Repetitive rating; pulse width limited by max junction temperature.
- ** Surface mounted on FR-4 board.
- *** Limited by TJmax , starting TJ=25°C, L = 0.3mH, Rg= 25 Ω , Vgs=-10V.

Electrical Characteristics(Tc =25°C Unless Otherwise Noted)

Cumbal	Donomotor	Test Conditions	HYG210P06LQ1		l lm it	
Symbol	Parameter	rest Conditions	Min	Тур	Max	Unit
Static Cha	racteristics					
BVDSS	Drain-Source Breakdown Voltage	V _{GS} =0V,I _{DS} =-250uA	-60	-	-	V
Ipss	Drain to Source Leekage Current	V _{DS} =-60V, V _{GS} =0V	-	-	-1	uA
IDSS	Drain-to-Source Leakage Current	TJ=125°C	-	-	-50	uA
VGS(th)	Gate Threshold Voltage	V _{DS} =V _{GS} , I _{DS} =-250uA	-1.0	-1.7	-3.0	V
Igss	Gate-Source Leakage Current	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	±100	nA
Procesu*	Drain-Source On-state Resistance	V _{GS} =-10V,I _D = -20A	-	19	25	mΩ
Rds(on)*	Dialii-Source Oil-state Resistance	V_{GS} =-4.5V, I_{D} = -20A		25	32	mΩ
Diode Cha	Diode Characteristics					
V _{SD} *	Diode Forward Voltage	Isp= -20A,Vgs=0V	-	-0.9	-1.3	V
trr	Reverse Recovery Time	lon- 204 dl/dt-1004/up	-	28	-	ns
Qrr	Reverse Recovery Charge	Isp= -20A,dl/dt=100A/us	-	25	-	nC

HYG210P06LQ1 D/U/V



Electrical Characteristics (Cont.) (Tc =25°C Unless Otherwise Noted)

O. mala al	Barrana	Took Conditions	HYG210P06LQ1			
Symbol	Parameter Test Conditions		Min	Тур	Max	Unit
Dynamic	Characteristics					
Rg	Gate Resistance	V_{GS} =0V, V_{DS} =0V, F=1MHz	-	6.4	-	Ω
Ciss	Input Capacitance	Vgs=0V,	-	3679	-	
Coss	Output Capacitance	VDS=-25V,	-	123	-	рF
Crss	Reverse Transfer Capacitance	Frequency=1.0MHz	-	60	-	
td(ON)	Turn-on Delay Time		-	11	-	
Tr	Turn-on Rise Time	V_{DD} = -25 V , R_{G} =3 Ω ,	-	17	-	no
td(OFF)	Turn-off Delay Time	IDS= -20A,VGS=-10V	-	73	-	ns
Tf	Turn-off Fall Time		-	31	-	
Gate Charge Characteristics						
Qg	Total Gate Charge	1/ 40\/ \/ 40\/	-	90	-	
Qgs	Gate-Source Charge	$V_{DS} = -48V, V_{GS} = -10V,$ $I_{D} = -20A,$	-	6	-	nC
Qgd	Gate-Drain Charge	ID20A,	-	18	-	

Note: *Pulse test; pulse width ≤ 300us, duty cycle ≤ 2%



Typical Operating Characteristics

Figure 1: Power Dissipation

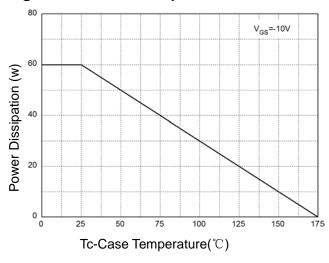


Figure 2: Drain Current

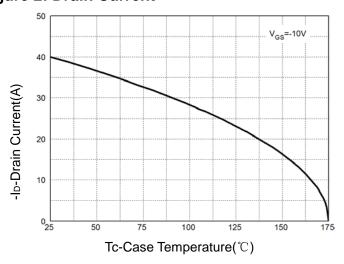


Figure 3: Safe Operation Area

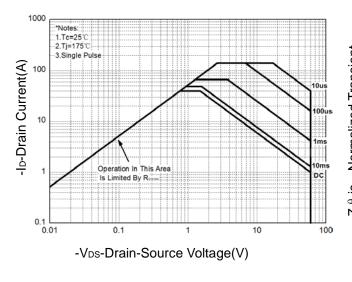
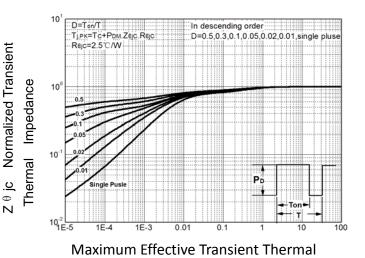


Figure 4: Thermal Transient Impedance



Impedance, Junction-to-Case

Figure 5: Output Characteristics

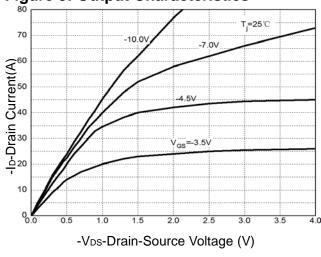
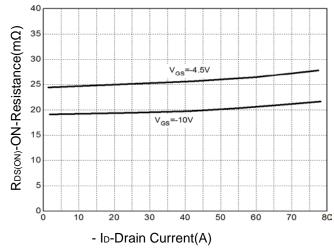


Figure 6: Drain-Source On Resistance





Typical Operating Characteristics(Cont.)

Figure 7: On-Resistance vs. Temperature

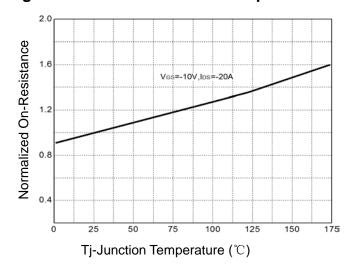


Figure 8: Source-Drain Diode Forward

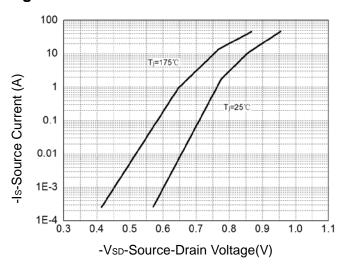


Figure 9: Capacitance Characteristics

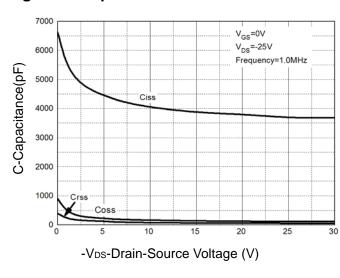
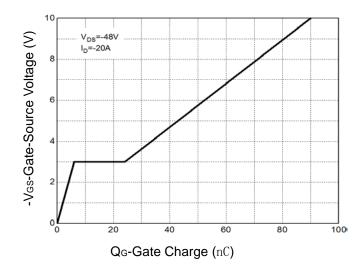
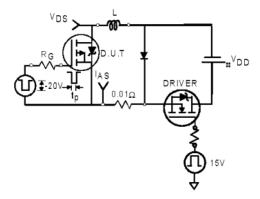


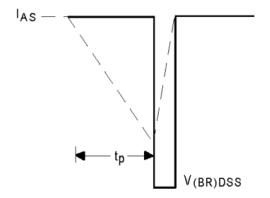
Figure 10: Gate Charge Characteristics



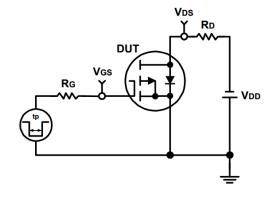


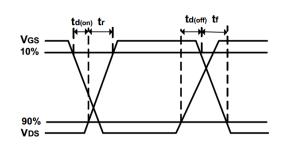
Avalanche Test Circuit



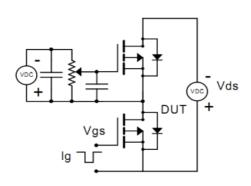


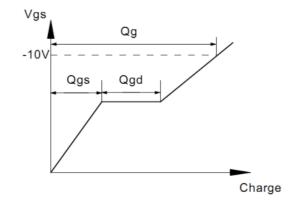
Switching Time Test Circuit





Gate Charge Test Circuit





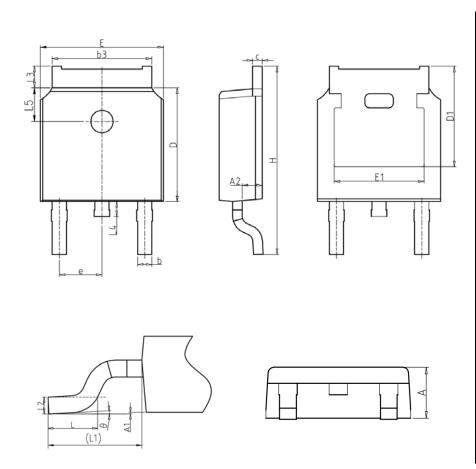


Device Per Unit

Package Type	Unit	Quantity
TO-252-2L	Tube	75
TO-252-2L	Reel	2500
TO-251-3L	Tube	75
TO-251-3S	Tube	75

Package Information

TO-252-2L

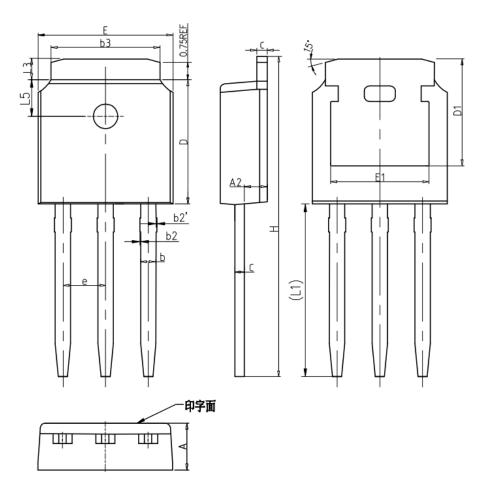


COMMON DIMENSIONS

SYMBOL mm MIN NOM MAX A 2.20 2.30 2.40 A1 0.00 - 0.20 A2 0.97 1.07 1.17 b 0.68 0.78 0.90 b3 5.20 5.33 5.50 c 0.43 0.53 0.63 D 5.98 6.10 6.22 D1 5.30REF E 6.40 6.60 6.80 E1 4.63 - - - - e 2.286BSC - H 9.40 10.10 10.50 L 1.38 1.50 1.75 - - - L2 0.51BSC - - - - - L3 0.88 - 1.28 - - - - L4 - - - - - - -					
MIN NOM MAX A 2.20 2.30 2.40 A1 0.00 - 0.20 A2 0.97 1.07 1.17 b 0.68 0.78 0.90 b3 5.20 5.33 5.50 c 0.43 0.53 0.63 D 5.98 6.10 6.22 D1 5.30REF E 6.40 6.60 6.80 E1 4.63 - - e 2.286BSC H 9.40 10.10 10.50 L 1.38 1.50 1.75 L1 2.90REF L2 0.51BSC L3 0.88 - 1.28 L4 - - 1.00 L5 1.65 1.80 1.95	CAMBOI	mm			
A1 0.00 - 0.20 A2 0.97 1.07 1.17 b 0.68 0.78 0.90 b3 5.20 5.33 5.50 c 0.43 0.53 0.63 D 5.98 6.10 6.22 D1 5.30REF E 6.40 6.60 6.80 E1 4.63 - - e 2.286BSC H 9.40 10.10 10.50 L 1.38 1.50 1.75 L1 2.90REF L2 0.51BSC L3 0.88 - 1.28 L4 - - 1.00 L5 1.65 1.80 1.95	STIVIDOL	MIN	NOM	MAX	
A2 0.97 1.07 1.17 b 0.68 0.78 0.90 b3 5.20 5.33 5.50 c 0.43 0.53 0.63 D 5.98 6.10 6.22 D1 5.30REF E 6.40 6.60 6.80 E1 4.63 - - e 2.286BSC H 9.40 10.10 10.50 L 1.38 1.50 1.75 L1 2.90REF L2 0.51BSC L3 0.88 - 1.28 L4 - - 1.00 L5 1.65 1.80 1.95	А	2.20	2.30	2.40	
b 0.68 0.78 0.90 b3 5.20 5.33 5.50 c 0.43 0.53 0.63 D 5.98 6.10 6.22 D1 5.30REF E 6.40 6.60 6.80 E1 4.63 - - e 2.286BSC H 9.40 10.10 10.50 L 1.38 1.50 1.75 L1 2.90REF L2 0.51BSC L3 0.88 - 1.28 L4 - - 1.00 L5 1.65 1.80 1.95	A1	0.00	-	0.20	
b3 5.20 5.33 5.50 c 0.43 0.53 0.63 D 5.98 6.10 6.22 D1 5.30REF E 6.40 6.60 6.80 E1 4.63 - - e 2.286BSC H 9.40 10.10 10.50 L 1.38 1.50 1.75 L1 2.90REF L2 0.51BSC L3 0.88 - 1.28 L4 - - 1.00 L5 1.65 1.80 1.95	A2	0.97	1.07	1.17	
c 0.43 0.53 0.63 D 5.98 6.10 6.22 D1 5.30REF E 6.40 6.60 6.80 E1 4.63 - - e 2.286BSC H 9.40 10.10 10.50 L 1.38 1.50 1.75 L1 2.90REF L2 0.51BSC L3 0.88 - 1.28 L4 - - 1.00 L5 1.65 1.80 1.95	b	0.68	0.78	0.90	
D 5.98 6.10 6.22 D1 5.30REF E 6.40 6.60 6.80 E1 4.63 - - e 2.286BSC H 9.40 10.10 10.50 L 1.38 1.50 1.75 L1 2.90REF L2 0.51BSC L3 0.88 - 1.28 L4 - - 1.00 L5 1.65 1.80 1.95	b3	5.20	5.33	5.50	
D1 5.30REF E 6.40 6.60 6.80 E1 4.63 - - e 2.286BSC H 9.40 10.10 10.50 L 1.38 1.50 1.75 L1 2.90REF L2 0.51BSC L3 0.88 - 1.28 L4 - - 1.00 L5 1.65 1.80 1.95	С	0.43	0.53	0.63	
E 6.40 6.60 6.80 E1 4.63 e 2.286BSC H 9.40 10.10 10.50 L 1.38 1.50 1.75 L1 2.90REF L2 0.51BSC L3 0.88 - 1.28 L4 1.00 L5 1.65 1.80 1.95	D	5.98	6.10	6.22	
E1 4.63 e 2.286BSC H 9.40 10.10 10.50 L 1.38 1.50 1.75 L1 2.90REF L2 0.51BSC L3 0.88 - 1.28 L4 1.00 L5 1.65 1.80 1.95	D1	5.30REF			
e 2.286BSC H 9.40 10.10 10.50 L 1.38 1.50 1.75 L1 2.90REF L2 0.51BSC L3 0.88 - 1.28 L4 1.00 L5 1.65 1.80 1.95	Е	6.40	6.60	6.80	
H 9.40 10.10 10.50 L 1.38 1.50 1.75 L1 2.90REF L2 0.51BSC L3 0.88 - 1.28 L4 - - 1.00 L5 1.65 1.80 1.95	E1	4.63	-	-	
L 1.38 1.50 1.75 L1 2.90REF L2 0.51BSC L3 0.88 - 1.28 L4 1.00 L5 1.65 1.80 1.95	е		2.286BS0		
L1 2.90REF L2 0.51BSC L3 0.88 - 1.28 L4 - - 1.00 L5 1.65 1.80 1.95	Н	9.40	10.10	10.50	
L2 0.51BSC L3 0.88 - 1.28 L4 - - 1.00 L5 1.65 1.80 1.95	L	1.38	1.50	1.75	
L3 0.88 - 1.28 L4 - - 1.00 L5 1.65 1.80 1.95	L1		2.90REF	•	
L4 - - 1.00 L5 1.65 1.80 1.95	L2	0.51BSC			
L5 1.65 1.80 1.95	L3	0.88	-	1.28	
	L4	-	-	1.00	
0 00 00	L5	1.65	1.80	1.95	
0 0 - 8	θ	0°	-	8°	



TO-251-3L

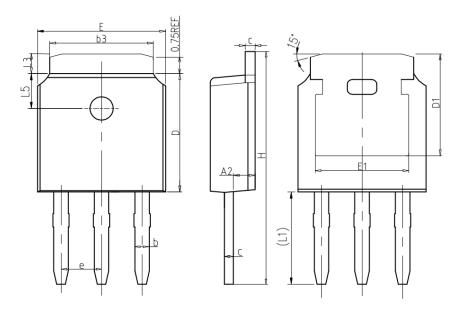


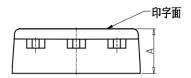
COMMON DIMENSIONS

CVMDOL	mm			
SYMBOL	MIN	NOM	MAX	
А	2.20	2.30	2.40	
A2	0.97	1.07	1.17	
b	0.68	0.78	0.90	
b2	0.00	0.04	0.10	
b2'	0.00	0.04	0.10	
b3	5.20	5.33	5.50	
С	0.43	0.53	0.63	
D	5.98	6.10	6.22	
D1	5.30REF			
E	6.40	6.60	6.80	
E1	4.63	-	-	
е	2.286BSC			
Н	16.22	16.52	16.82	
L1	9.15	9.40	9.65	
L3	0.88	1.02	1.28	
L5	1.65	1.80	1.95	



TO-251-3S



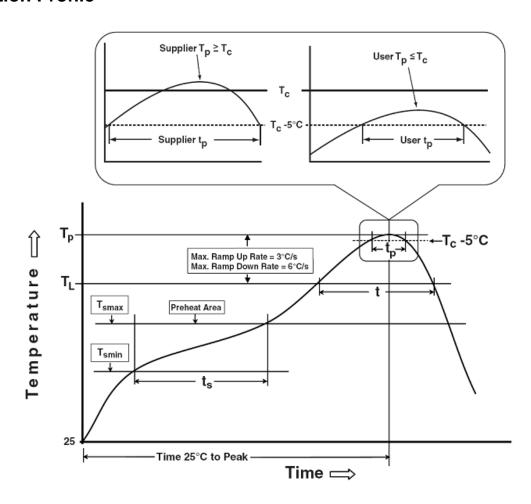


COMMON DIMENSIONS

CVMPOL	mm			
SYMBOL	MIN	NOM	MAX	
А	2.20	2.30	2.40	
A2	0.97	1.07	1.17	
b	0.68	0.78	0.90	
b3	5.20	5.33	5.50	
С	0.43	0.53	0.63	
D	5.98	6.10	6.22	
D1		5.30REF		
E	6.40	6.60	6.80	
E1	4.63	ı	ı	
е		2.286BSC		
Н	10.00	11.22	11.44	
L1	3.90	4.10	4.30	
L3	0.88	1.02	1.28	
L5	1.65	1.80	1.95	



Classification Profile



Classification Reflow Profiles

Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly		
Preheat & Soak	100 °C	150 °C		
Temperature min (T _{smin})	150 °C	200 °C		
Temperature max (T _{smax})				
Time (Tsmin to Tsmax) (t₅)	60-120 seconds	60-120 seconds		
Average ramp-up rate	3 °C/second max.	3°C/second max.		
(T _{smax} to T _P)	5 C/second max.	5 C/Second max.		
Liquidous temperature (T _L)	183 °C	217 °C		
Time at liquidous (t _L)	60-150 seconds	60-150 seconds		
Peak package body Temperature	See Classification Temp in table 1	See Classification Temp in table 2		
(T _p)*	See Classification Temp in table 1	See Classification Temp in table 2		
Time (t _P)** within 5°C of the specified	20** seconds	30** seconds		
classification temperature (T _c)	20 seconds	30 Seconds		
Average ramp-down rate (Tp to Tsmax)	6 °C/second max.	6 °C/second max.		
Time 25°C to peak temperature	6 minutes max.	8 minutes max.		

^{*}Tolerance for peak profile Temperature (Tp) is defined as a supplier minimum and a user maximum.

^{**} Tolerance for time at peak profile temperature (t_p) is defined as a supplier minimum and a user maximum.

HYG210P06LQ1 D/U/V



Table 1.SnPb Eutectic Process – Classification Temperatures (Tc)

Package	Volume mm³	Volume mm³
Thickness	<350	≥350
<2.5 mm	235 °C	220 °C
≥2.5 mm	220 °C	220 °C

Table 2.Pb-free Process – Classification Temperatures (Tc)

Package	Volume mm³	Volume mm³	Volume mm³
Thickness	<350	350-2000	≥2000
<1.6 mm	260 °C	260 °C	260 °C
1.6 mm – 2.5 mm	260 °C	250 °C	245 °C
≥2.5 mm	250 °C	245 °C	245 °C

Reliability Test Program

Test item	Method	Description
SOLDERABILITY	JESD-22, B102	5 Sec, 245°C
HTRB	JESD-22, A108	168 Hrs/500 Hrs/1000Hrs, Bias @ 150°C
PCT	JESD-22, A102	96 Hrs, 100%RH, 2atm, 121°C
ТСТ	JESD-22, A104	500 Cycles, -55°C~150°C

Customer Service

Worldwide Sales and Service: sales@hymexa.com Technical Support: Technology@hymexa.com

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